National Semiconductor

CD4514BM/CD4514BC, CD4515BM/CD4515BC 4-Bit Latched/4-to-16 Line Decoders

General Description

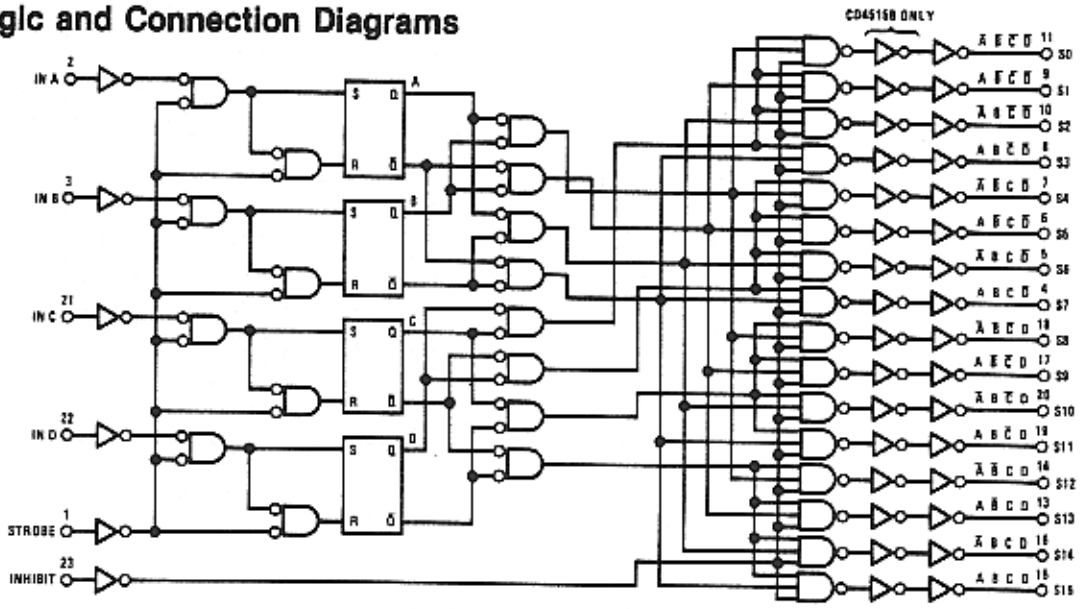
The CD4514B and CD4515B are 4-to-16 line decoders with latched inputs implemented with complementary MOS (CMOS) circuits constructed with N- and P-channel enhancement mode transistors. These circuits are primarily used in decoding applications where low power dissipation and/or high noise immunity is required.

The CD4514B (output active high option) presents a logical "1" at the selected output, whereas the CD4515B presents a logical "0" at the selected output. The input latches are R-S type flip-flops, which hold the last input data presented prior to the strobe transition from "1" to "0". This input data is decoded and the corresponding output is activated. An output inhibit line is also available.

Features

- Wide supply voltage range — 3.0V to 15V
- High noise immunity — 0.45 V_{DD} (typ.)
- Low power TTL compatibility — fan out of 2 driving 74L
- Low quiescent power dissipation — 0.025 μW/package @ 5.0 V_{DC}
- Single supply operation
- Input impedance = $10^{12}\Omega$ typically
- Plug-in replacement for MC14514, MC14515

Logic and Connection Diagrams



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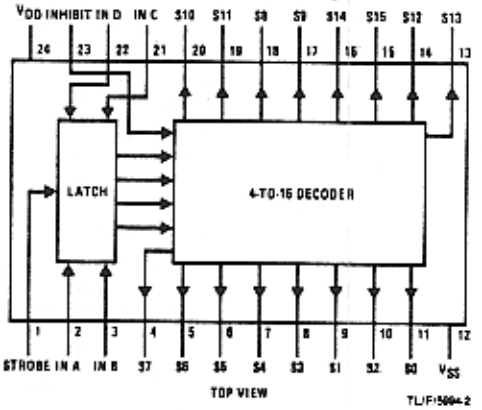
Dual-In-Line Package



TL/F/5694-2

Order Number CD4514BMJ, CD4514BCJ, CD4515BMJ or CD4515BCJ
See NS Package J24A

Order Number CD4514BMN, CD4514BCN, CD4515BMN or CD4515BCN
See NS Package N24A

5

Absolute Maximum Ratings

(Notes 1 and 2)

V_{DD} DC Supply Voltage	−0.5V to +18V
V_{IN} Input Voltage	−0.5V to V_{DD} + 0.5V
T_S Storage Temperature Range	−65°C to +150°C
P_D Package Dissipation	500 mW
T_L Lead Temperature (Soldering, 10 seconds)	260°C

Recommended Operating Conditions

(Note 2)

V_{DD} DC Supply Voltage	3V to 15V
V_{IN} Input Voltage	0 to V_{DD}
T_A Operating Temperature Range	
CD4514BM, CD4515BM	−55°C to +125°C
CD4514BC, CD4515BC	−40°C to +85°C

DC Electrical Characteristics CD4514BM, CD4515BM (Note 2)

SYM	PARAMETER	CONDITIONS	−55°C		25°C			125°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V, V_{IN} = V_{DD} or V_{SS}		5.0		0.005	5.0		150	μA
		V_{DD} = 10V, V_{IN} = V_{DD} or V_{SS}		10.0		0.010	10.0		300	μA
		V_{DD} = 15V, V_{IN} = V_{DD} or V_{SS}		20.0		0.015	20.0		600	μA
V_{OL}	Low Level Output Voltage	V_{IH} = V_{DD}, $\|I_O\|$ < 1 μA								
		V_{DD} = 5V, V_{IL} = 0V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	V_{IH} = V_{DD}, $\|I_O\|$ < 1 μA								
		V_{DD} = 5V, V_{IL} = 0V	4.95		4.95	5.0		4.95		V
		V_{DD} = 10V	9.95		9.95	10.0		9.95		V
		V_{DD} = 15V	14.95		14.95	15.0		14.95		V
V_{IL}	Low Level Input Voltage	V_O = 0.5V or 4.5V								
		V_{DD} = 5V, $\|I_O\|$ < 1 μA		1.5		2.25	1.5		1.5	V
		V_{DD} = 10V, V_O = 1.0V or 9.0V		3.0		4.50	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	V_O = 0.5V or 4.5V								
		V_{DD} = 5V, $\|I_O\|$ < 1 μA	3.5		3.5	2.75		3.5		V
		V_{DD} = 10V, V_O = 1.0V or 9.0V	7.0		7.0	5.50		7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I_{OL}	Low Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.64		0.51	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.6		1.3	2.25		0.90		mA
		V_{DD} = 15V, V_O = 1.5V	4.2		3.4	8.80		2.40		mA
I_{OH}	High Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.64		−0.51	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.6		−1.3	−2.25		−0.90		mA
		V_{DD} = 15V, V_O = 13.5V	−4.2		−3.4	−8.80		−2.40		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.1		-10^{-5}	−0.1		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.1		10^{-5}	0.1		1.0	μA

DC Electrical Characteristics CD4514BC, CD4515BC (Note 2)

SYM	PARAMETER	CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V, V_{IN} = V_{DD} or V_{SS}		20		0.005	20		150	μA
		V_{DD} = 10V, V_{IN} = V_{DD} or V_{SS}		40		0.010	40		300	μA
		V_{DD} = 15V, V_{IN} = V_{DD} or V_{SS}		80		0.015	80		600	μA
V_{OL}	Low Level Output Voltage	V_{IL} = 0V, V_{IH} = V_{DD}, $\|I_O\|$ < 1 μA								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	V_{IL} = 0V, V_{IH} = V_{DD}, $\|I_O\|$ < 1 μA								
		V_{DD} = 5V	4.95		4.95	5.0		4.95		V
		V_{DD} = 10V	9.95		9.95	10.0		9.95		V
		V_{DD} = 15V	14.95		14.95	15.0		14.95		V

DC Electrical Characteristics (Continued) CD4514BC, CD4515BC (Note 2)

SYM	PARAMETER	CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
V_{IL}	Low Level Input Voltage	$\|I_O\| < 1\ \mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
		V_{DD} = 10V, V_O = 1.0V or 9.0V		3.0		4.50	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	$\|I_O\| < 1\ \mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
		V_{DD} = 10V, V_O = 1.0V or 9.0V	7.0		7.0	5.50		7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I_{OL}	Low Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.90		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.90		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.3		-10^{-5}	−0.3		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.3		10^{-5}	0.3		1.0	μA

AC Electrical Characteristics All types C_L = 50 pF, T_A = 25°C, $t_r = t_f$ = 20 ns unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
t_{THL}, t_{TLH}	Transition Times	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
t_{PLH}, t_{PHL}	Propagation Delay Times	V_{DD} = 5V		550	1100	ns
		V_{DD} = 10V		225	450	ns
		V_{DD} = 15V		150	300	ns
t_{PLH}, t_{PHL}	Inhibit Propagation Delay Times	V_{DD} = 5V		400	800	ns
		V_{DD} = 10V		150	300	ns
		V_{DD} = 15V		100	200	ns
t_{SU}	Set Up Time	V_{DD} = 5V		125	250	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		38	75	ns
t_{WH}	Strobe Pulse Width	V_{DD} = 5V		175	350	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		38	75	ns
C_{PD}	Power Dissipation Capacitance	Per Package, (Note 5)		150		pF
C_{IN}	Input Capacitance	Any Input, (Note 4)		5	7.5	pF

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

Note 4: Capacitance is guaranteed by periodic testing.

Note 5: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C&74C Family Characteristics application note, AN-90.

5

Truth Table

DECODE TRUTH TABLE (Strobe = 1)

INHIBIT	DATA INPUTS				SELECTED OUTPUT CD4514 = LOGIC "1" CD4515 = LOGIC "0"
	D	C	B	A	
0	0	0	0	0	S0
0	0	0	0	1	S1
0	0	0	1	0	S2
0	0	0	1	1	S3
0	0	1	0	0	S4
0	0	1	0	1	S5
0	0	1	1	0	S6
0	0	1	1	1	S7
0	1	0	0	0	S8
0	1	0	0	1	S9
0	1	0	1	0	S10
0	1	0	1	1	S11
0	1	1	0	0	S12
0	1	1	0	1	S13
0	1	1	1	0	S14
0	1	1	1	1	S15
1	X	X	X	X	All Outputs = 0, CD4514 All Outputs = 1, CD4515

X = Don't care

AC Test Circuit and Switching Time Waveforms

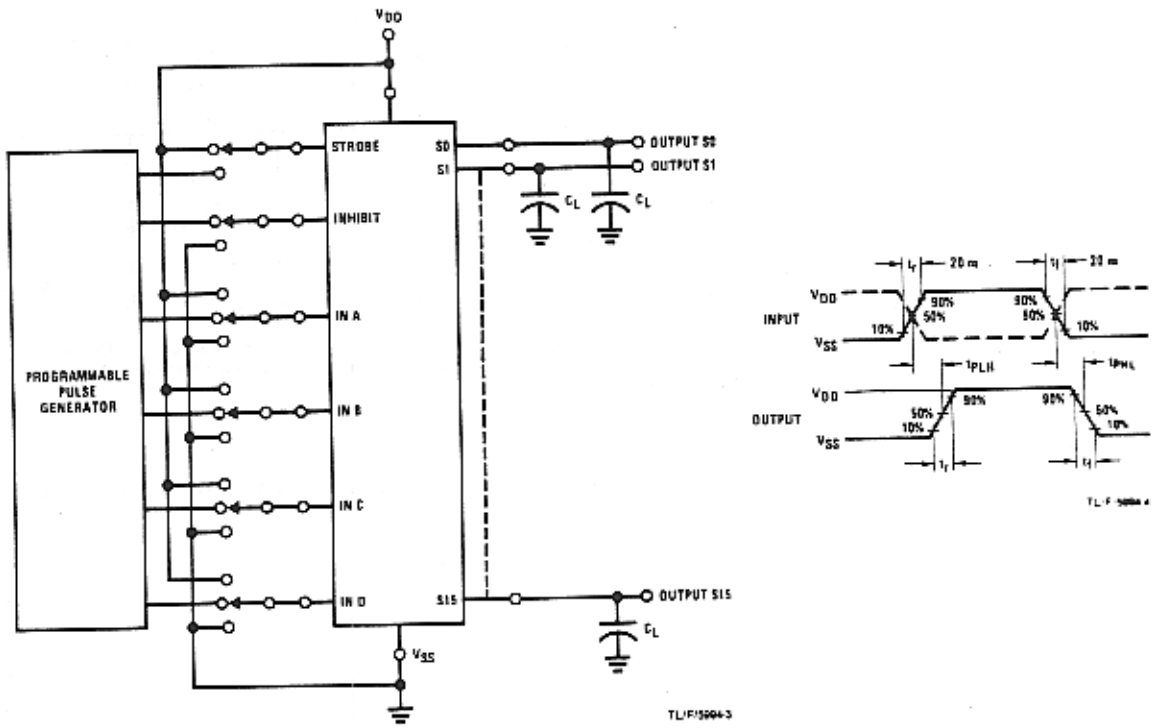


FIGURE 1

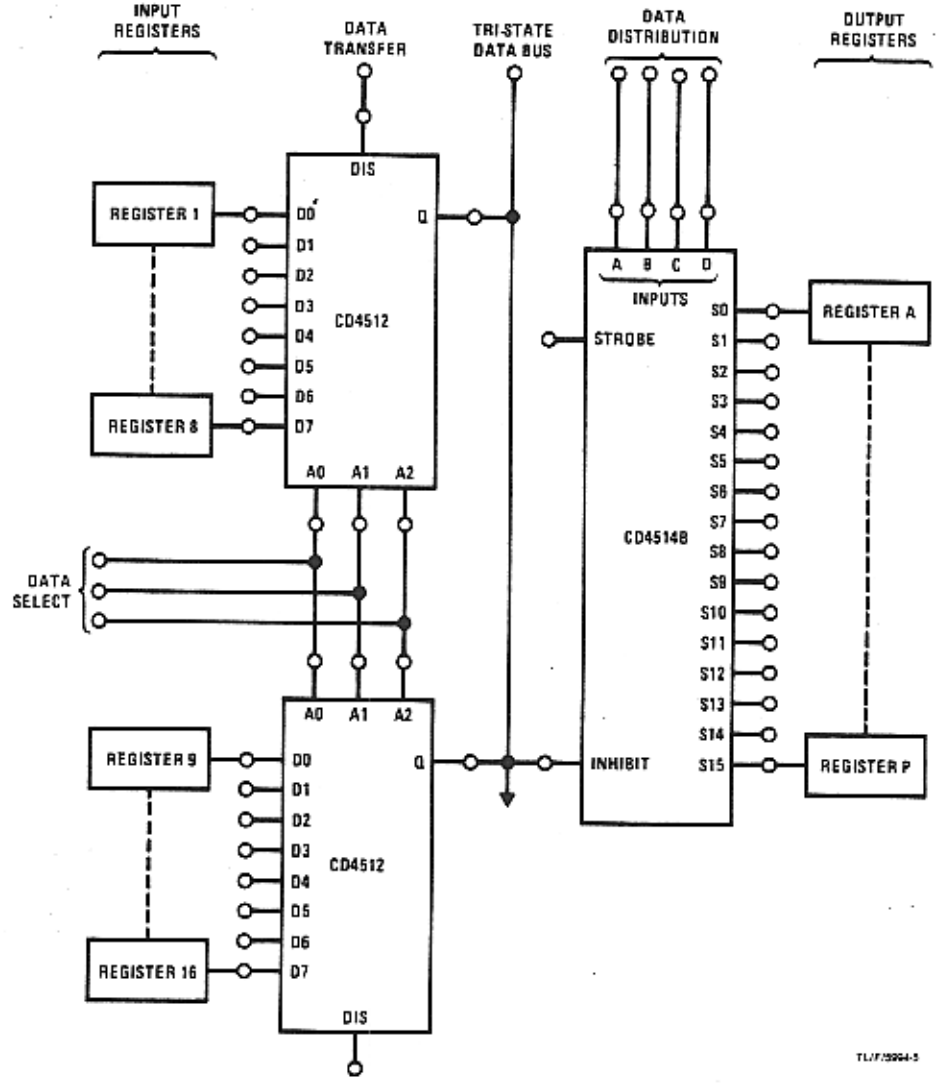
Applications

Two CD4512 8-channel data selectors are used here with the CD4514B 4-bit latch/decoder to effect a complex data routing system. A total of 16 inputs from data registers are selected and transferred via a TRI-STATE data bus to a data distributor for rearrangement and entry into 16 output registers. In this way sequential data can be re-routed or intermixed according to patterns determined by data select and distribution inputs.

Data is placed into the routing scheme via the 8 inputs on both CD4512 data selectors. One register is assigned to each input. The signals on A0, A1 and A2 choose 1-of-8 inputs for transfer out to the TRI-STATE data bus. A fourth signal, labelled Dis, disables one of the CD4512 selectors, assuring transfer of data from only one register.

In addition to a choice of input registers, 1–16, the rate of transfer of the sequential information can also be varied. That is, if the CD4512 were addressed at a rate that is 8 times faster than the shift frequency of the input registers, the most significant bit (MSB) from each register could be selected for transfer to the data bus. Therefore, all of the most significant bits from all of the registers can be transferred to the data bus before the next most significant bit is presented for transfer by the input registers.

Information from the TRI-STATE bus is redistributed by the CD4514B 4-bit latch/decoder. Using the 4-bit address, INA–IND, the information on the inhibit line can be transferred to the addressed output line to the desired output registers, A–P. This distribution of data bits to the output registers can be made in many complex patterns. For example, all of the most significant bits from the input registers can be routed into output register A, all of the next most significant bits into register B, etc. In this way horizontal, vertical, or other methods of data slicing can be implemented.



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